18-bit Universal Bus Driver with 3-state Outputs

HITACHI

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Description

The HD74ALVCH16835 is an 18-bit universal bus driver designed for 2.3 V to 3.6 V V_{CC} operation. Data flow from A to Y is controlled by the output enable (\overline{OE}). The device operates in the transparent mode when the latch enable (LE) input is high. The A data is latched if the clock (CLK) input is held at a high or low logic level. If the LE is low, the A bus data is stored in the latch/flip flop on the low to high transition of CLK. When \overline{OE} is high, the outputs are in the high impedance state. To ensure the high impedance state during power up or power down, the output ebable (\overline{OE}) input should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current sinking capability of the driver. Active bus hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

Features

- Supports unregulated battery operation down to 2.7 V
- Bus hold on data inputs eliminates the need for external pullup resistors.
- Distributed V_{CC} and GND pin configuration minimizes high speed switching noise.



Function Table

Inputs

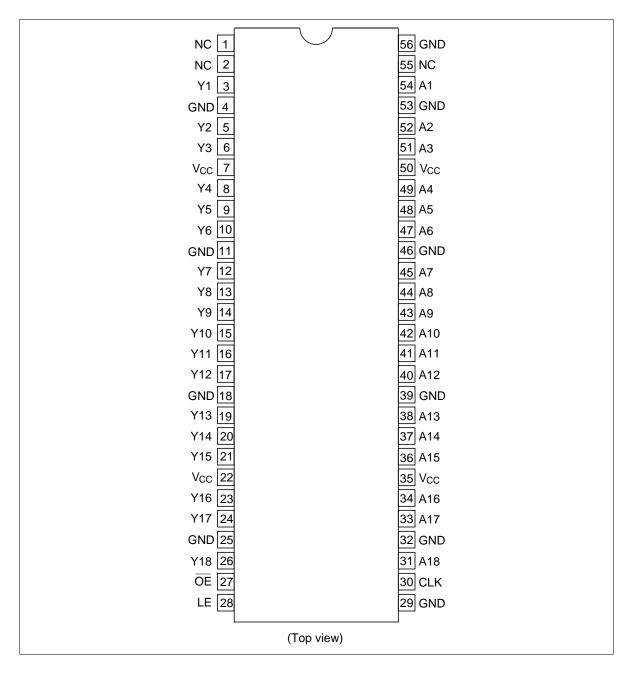
OE	LE	CLK	Α	Output Y
Н	Х	Х	X	Z
L	Н	Х	L	L
L	Н	Х	Н	Н
L	L	\uparrow	L	L
L	L	\uparrow	Н	Н
L	L	Н	Х	Y ₀ *1
L	L	L	Х	Y ₀ *2

H: High level
L: Low level
X: Immaterial
Z: High impedance
↑: Low to high transition

Notes: 1. Output level before the indicated steady-state input conditions were established, provided that CLK was high before LE went low.

2. Output level before the indicated steady-state input conditions were established.

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V _{cc}	-0.5 to 4.6	V	
Input voltage range *1	V _i	-0.5 to 4.6	V	
Output voltage range *1, 2	Vo	-0.5 to V _{cc} +0.5	V	
Input clamp current	I _{IK}	-50	mA	V ₁ < 0
Output clamp current	I _{ok}	±50	mA	$V_{o} < 0 \text{ or } V_{o} > V_{cc}$
Continuous output current	Io	±50	mA	$V_{\rm o}$ = 0 to $V_{\rm cc}$
V _{cc} , GND current / pin	I _{CC} or I _{GND}	±100	mA	
Maximum power dissipation at Ta = 55°C (in still air) ³	P _T	1	W	TSSOP
Storage temperature range	Tstg	-65 to 150	°C	

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating condition" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Notes: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp current ratings are observed.

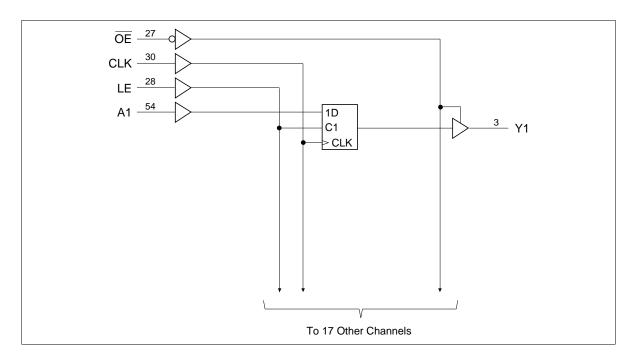
- 2. The input and output positive-voltage ratings may be exceeded up to 4.6 V if the input and output clamp-current ratings are observed.
- 3. The maximum power dissipation is calculated using a junction temperature of 150° C and board trace length of 750 mils.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage	V _{cc}	2.3	3.6	V	
Input voltage	Vı	0	V _{cc}	V	
Output voltage	Vo	0	V _{cc}	V	
High-level output current	I _{OH}	_	-12	mA	V _{cc} = 2.3 V
		_	-12		$V_{CC} = 2.7 \text{ V}$
		_	-24		V _{cc} = 3.0 V
Low-level output current	I _{OL}	_	12	mA	V _{cc} = 2.3 V
		_	12		$V_{CC} = 2.7 \text{ V}$
		_	24		V _{CC} = 3.0 V
Input transition rise or fall rate	Δt/Δν	0	10	ns/V	
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating control pins must be held high or low.

Logic Diagram



Electrical Characteristics

Ta = -40 to 85°C

Item	Symbol	V _{cc} (V)	Min	Max	- Unit	Test Conditions
Input voltage	V _{IH}	2.3 to 2.7	1.7	_	V	
		2.7 to 3.6	2.0	_	_	
	V _{IL}	2.3 to 2.7	_	0.7	V	
		2.7 to 3.6	_	0.8	_	
Output voltage	V _{OH}	Min to Max	V _{cc} -0.2	_	V	$I_{OH} = -100 \mu A$
		2.3	2.0	_	-	$I_{OH} = -6 \text{ mA}, V_{IH} = 1.7 \text{ V}$
		2.3	1.7	_	-	$I_{OH} = -12 \text{ mA}, V_{IH} = 1.7 \text{ V}$
		2.7	2.2	_	-	$I_{OH} = -12 \text{ mA}, V_{IH} = 2.0 \text{ V}$
		3.0	2.4	_	-	$I_{OH} = -12 \text{ mA}, V_{IH} = 2.0 \text{ V}$
		3.0	2.0	_	-	$I_{OH} = -24 \text{ mA}, V_{IH} = 2.0 \text{ V}$
	V _{OL}	Min to Max	_	0.2	V	I _{OL} = 100 μA
		2.3	_	0.4	=	$I_{OL} = 6 \text{ mA}, V_{IL} = 0.7 \text{ V}$
		2.3	_	0.7	=	$I_{OL} = 12 \text{ mA}, V_{IL} = 0.7 \text{ V}$
		2.7	_	0.4	_	I_{OL} = 12 mA, V_{IL} = 0.8 V
		3.0	_	0.55	_	$I_{OL} = 24 \text{ mA}, V_{IL} = 0.8 \text{ V}$
Input current	I _{IN}	3.6	_	±5.0	μΑ	$V_{IN} = V_{CC}$ or GND
	I _{IN(hold)}	2.3	_	_	μΑ	$V_{IN} = 0.7 \text{ V}$
		2.3	-45	_	_	$\overline{V_{IN}} = 1.7 \text{ V}$
		3.0	75	_	=	$V_{IN} = 0.8 \text{ V}$
		3.0	-75	_	_	$V_{IN} = 2.0 \text{ V}$
Off state output current	l _{oz}	3.6	_	±10	μΑ	$V_{OUT} = V_{CC}$ or GND
Quiescent supply current	I _{cc}	3.6	_	40	μΑ	$V_{IN} = V_{CC}$ or GND
	ΔI_{CC}	3.0 to 3.6	_	750	μΑ	One input at (V_{cc} –0.6)V, other inputs at V_{cc} or GND

Switching Characteristics (Ta = -40 to 85°C)

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	From (Input)	To (Output)
Maximum clock	f _{max}	2.5±0.2	150	_	_	MHz		
frequency		2.7	150	_	_			
		3.3±0.3	150	_	_			
Propagation delay time	t _{PLH}	2.5±0.2	1.3	_	5.0	ns	A	Υ
	$t_{\scriptscriptstylePHL}$	2.7	_	_	4.2			
		3.3±0.3	1.0	_	3.6	 *		
		2.5±0.2	1.8	_	5.8	_	LE	Υ
		2.7	_	_	4.9	_		
		3.3±0.3	1.3	_	4.2	_		
		2.5±0.2	1.9	_	5.5	_	CLK	Υ
		2.7	_	_	5.2	_		
		3.3±0.3	1.4	_	4.5	 *		
Output enable time	t _{zH}	2.5±0.2	1.5	_	5.5	ns	ŌĒ	Υ
	t_{zL}	2.7	_	_	5.6			
		3.3±0.3	1.1	_	4.6	 *		
Output disable time	t _{HZ}	2.5±0.2	2.1	_	4.5	ns	ŌĒ	Υ
	t_{LZ}	2.7	_	_	4.3	_		
		3.3±0.3	1.3	_	3.9	_		
Input capacitance	C _{IN}	3.3	_	3.5	_	pF	Control inputs	i
		3.3	_	6.0	_	_	Data inputs	
Output capacitance	C _o	3.3	_	7.0	_	pF	A or Y ports	

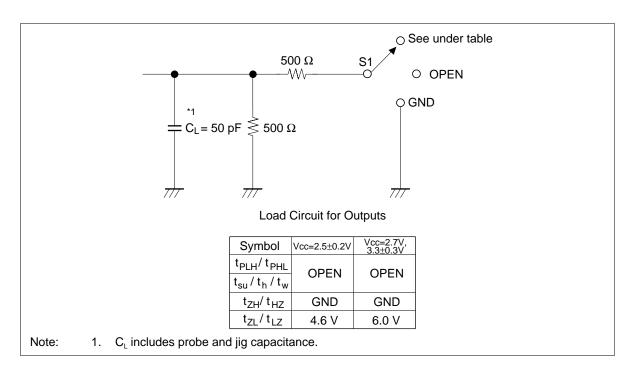
Switching Characteristics (Ta = -40 to 85°C) (cont)

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	From (Input)
Setup time	t _{su}	2.5±0.2	2.2	_	_	ns	Data before CLK↑
		2.7	2.1	_	_		
		3.3±0.3	1.7	_	_		
		2.5±0.2	1.9	_	_		Data before LE↓
		2.7	1.6	_	_		CLK "H"
		3.3±0.3	1.5	_	_		
		2.5±0.2	1.3	_	_		Data before LE↓
		2.7	1.1	_	_		CLK "L"
		3.3±0.3	1.0	_	_		
Hold time	t _h	2.5±0.2	0.6	_	_	ns	Data after CLK↑
		2.7	0.6	_	_		
		3.3±0.3	0.7	_	_		
		2.5±0.2	1.4	_	_		Data after LE↓
		2.7	1.7	_	_		CLK "H" or "L"
		3.3±0.3	1.4	_	_		
Pulse width	t _w	2.5±0.2	3.3	_	_	ns	LE "H"
		2.7	3.3	_	_	_	
		3.3±0.3	3.3	_	_	_	
		2.5±0.2	3.3	_	_	_	CLK "H" or "L"
		2.7	3.3	_	_	_	
		3.3±0.3	3.3	_	_	_	

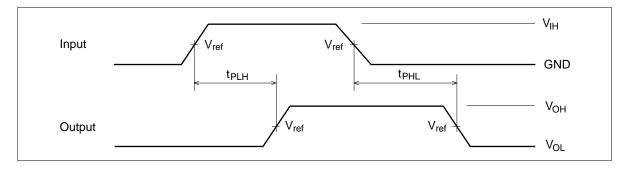
Switching Characteristics (Ta = 0 to 65° C)

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	FROM (Input)	TO (Output)
Propagation delay time	$t_{\scriptscriptstyle PLH},t_{\scriptscriptstyle PHL}$	3.3±0.15	5 1.7	_	4.5	ns	CLK	Υ

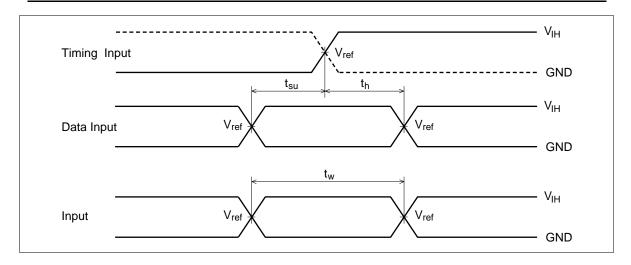
Test Circuit



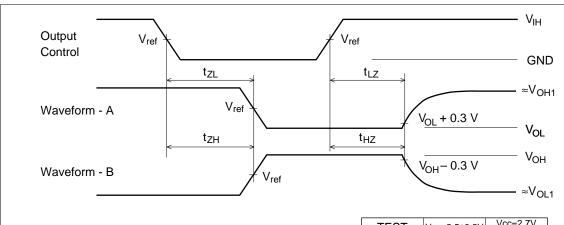
Waveforms-1



Waveforms-2



Waveforms - 3



 TEST
 Vcc=2.5±0.2V
 Vcc=2.7V, 3.3±0.3V

 V_{IH}
 2.3 V
 2.7 V

 V_{ref}
 1.2 V
 1.5 V

 V_{OH1}
 2.3 V
 3.0 V

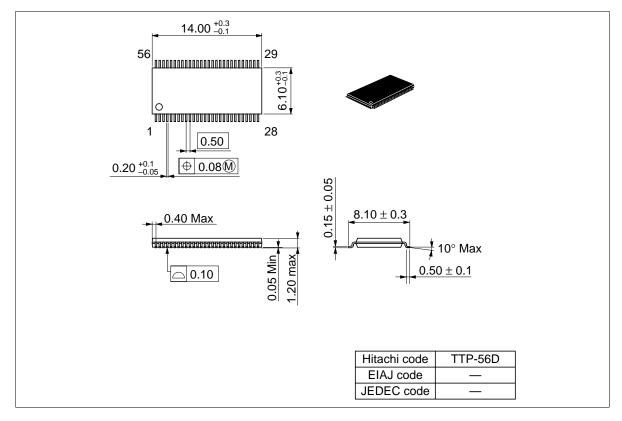
 V_{OL1}
 GND
 GND

Notes:

- 1. All input pulses are supplied by generators having the following characteristics: PRR \leq 10MHz, $Z_{\rm O}$ = 50 Ω , $t_{\rm r} \leq$ 2.5 ns, $t_{\rm f} \leq$ 2.5 ns.
- 2. Waveform—A is for an output with internal conditions such that the output is low except when disabled by the output control.
- 3. Waveform—B is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. The outputs are measured one at a time with one transition per measurement.

Package Dimensions

Unit: mm



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